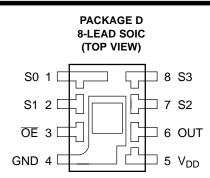


PROGRAMMABLE LIGHT-TO-FREQUENCY CONVERTERS

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- High-Resolution Conversion of Light Intensity to Frequency With No External Components
- Programmable Sensitivity and Full-Scale Output Frequency
- Communicates Directly With a Microcontroller
- High Irradiance Responsivity . . .
 830 Hz/(μW/cm²) Typical at 640 nm
- Single-Supply Operation . . . 2.7 V to 5.5 V
- Power-Down Feature . . . 5 μA Typical
- Nonlinearity Error Typically 0.2% at 100 kHz
- Stable 200 ppm/°C Temperature Coefficient
- Low-Profile Surface-Mount Package

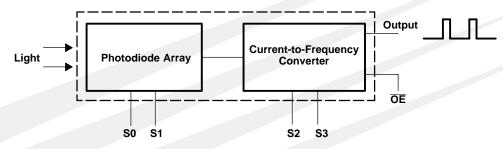


Description

The TSL230RD programmable light-to-frequency converter combines a configurable silicon photodiode and a current-to-frequency converter on single monolithic CMOS integrated circuit. The output can be either a pulse train or a square wave (50% duty cycle) with frequency directly proportional to light intensity. Device sensitivity is selectable in three ranges, providing two decades of adjustment. The full-scale output frequency can be scaled by one of four preset values. All inputs and the output are TTL compatible, allowing direct two-way communication with a microcontroller for programming and output interface. The output enable (\overline{OE}) places the output in the high-impedance state for multiple-unit sharing of a microcontroller input line.

The device has been temperature compensated for the ultraviolet-to-visible light range of 320 nm to 700 nm and responds over the light range of 320 nm to 1050 nm. It is characterized over the temperature range of -25°C to 70°C.

Functional Block Diagram



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Terminal Functions

TERMII	NAL	TYPE	DESCRIPTION				
NAME	NO.	ITPE	DESCRIPTION				
GND	4		Ground				
ŌĒ	3	I	Enable for f _O (active low)				
OUT	6	0	Scaled-frequency (f _O) output				
S0, S1	1, 2	ı	Sensitivity-select inputs				
S2, S3	7, 8	ı	f _O scaling-select inputs				
V_{DD}	5		Supply voltage				

Selectable Options

S 1	S0	SENSITIVITY			
L	L	Power down			
L	Н	1×			
Н	L	10×			
Н	Н	100×			

S3	S2	f _O SCALING (divide-by)				
L	L	1				
L	Н	2				
Н	L	10				
Н	Н	100				

Absolute Maximum Ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V _{DD} (see Note 1)	6 V
Input voltage range, all inputs, V _I 0.3 V to	V _{DD} + 0.3 V
Operating free-air temperature range, T _A 2	25°C to 70°C
Storage temperature range	25°C to 85°C
Solder conditions in accordance with JEDEC J-STD-020A, maximum temperature	240°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to GND.

Recommended Operating Conditions

			MIN	NOM	MAX	UNIT
Supply voltage, V _{DD}			2.7	5	5.5	V
High-level input voltage, V _{IH}	V _{DD} = 4.5 V to 5.5 V		2		V_{DD}	V
Low-level input voltage, V _{IL}	V _{DD} = 4.5 V to 5.5 V		0		8.0	V
Operating free-air temperature range, T _A		- 25		70	°C	



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Electrical Characteristics at $T_A = 25^{\circ}C$, $V_{DD} = 5$ V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{OH}	High-level output voltage	$I_{OH} = -4 \text{ mA}$	4	4.5		V
V_{OL}	Low-level output voltage	I _{OL} = 4 mA		0.25	0.4	V
I _{IH}	High-level input current				5	μΑ
I _{IL}	Low-level input current				5	μΑ
	Committee accomment	Power-on mode		2	3	mA
I _{DD}	Supply current	Power-down mode		5	12	μΑ
F.S.	Full-scale frequency (See Note 2)	S0=S1=H, S2=S3=L	1.1			MHz
	Temperature coefficient of output frequency	$\lambda \leq 700$ nm (See Note 3)		±200		ppm/°C
k _{SVS}	Supply voltage sensitivity	V _{DD} = 5 V ±10%		±0.5		%/V

NOTES: 2. Full-scale frequency is the maximum operating frequency of the device without saturation.

Operating Characteristics at V_{DD} = 5 V, T_A = 25°C, E_e = 120 μ W/cm², λ_p = 640 nm (unless otherwise noted)

			T				
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
		S0 = S1 = H, S2 = S3 = L	80	100	120	kHz	
	Output frequency	S1 = H, S0 = S2 = S3 = L	8	10	12	kHz	
,		S0 = H, S1 = S2 = S3 = L	0.8	1	1.2	kHz	
f _O		S0 = S1 = S2 = H, S3 = L	40	50	60	kHz	
		S0 = S1 = S3 = H, S2 = L	8	10	12	kHz	
		S0 = S1 = S2 = S3 = H	0.8	1	1.2	kHz	
f_D	Dark frequency	E _e = 0, S0 = S1 = H, S2 = S3 = L		0.4	10	Hz	
R _e	Responsivity	S0 = S1 = H, S2 = S3 = L		0.83		kHz/ (μW/cm ²)	
	Output makes should be	S2 = S3 = L	125		600	ns	
t _w	Output pulse duration	S2 or S3 = H		1/2f _O		S	
		$f_O = 0$ MHz to 10 kHz		±0.1%		%F.S.	
	Nonlinearity (See Notes 4 and 5)	$f_O = 0$ MHz to 100 kHz		±0.2%		%F.S.	
		$f_O = 0$ MHz to 1 MHz		±0.5%		%F.S.	
	Recovery from power down				100	μs	
	Step response to full-scale step input		1 pulse of new frequency plus 1 μs		uency		
	Response time to programming change		2 periods of new principal frequency plus 1 μs (Note 6)				
	Response time to output enable (OE)			50	150	ns	

NOTES: 4. Nonlinearity is defined as the deviation of fo from a straight line between zero and full scale, expressed as a percent of full scale.

5. Nonlinearity test condition: S0 = S1 = H, S2 = S3 = L.

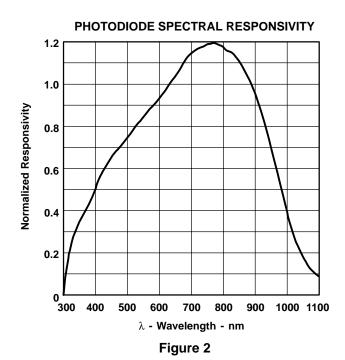
6. Principal frequency is the internal oscillator frequency, equivalent to divide-by-1 output selection.



^{3.} The temperature coefficient of output frequency is measured with constant irradiance as the temperature is varied between -25°C and 70°C. The constant irradiance is sufficiently high that the output frequency is much greater than the dark frequency over the entire temperature range.

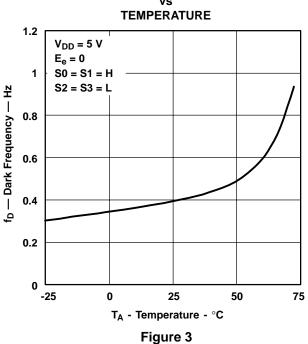
TYPICAL CHARACTERISTICS

OUTPUT FREQUENCY IRRADIANCE 1000 $V_{DD} = 5 V$ $\lambda_p = 640 \text{ nm}$ 100 . T_A = 25°C Output Frequency (fo - fp) — kHz S2 = S3 = L10 S0 = H, S1 = H0.1 S0 = L, S1 = H0.01 S0 = H, S1 = L0.001 0.001 0.01 0.1 10 100 1k 10k 100k 1M E_e - Irradiance - μ W/cm²



DARK FREQUENCY vs TEMPERATURE

Figure 1



TEMPERATURE COEFFICIENT OF OUTPUT FREQUENCY

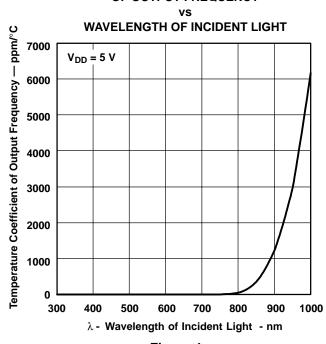


Figure 4

5.5

5

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TYPICAL CHARACTERISTICS

OUTPUT FREQUENCY SUPPLY VOLTAGE 1.010 T_A = 25°C f_O = 100 kHz 1.005 Normalized Output Freduency 0.995 0.990 0.985 0.980 _______2.5

Figure 5

4

V_{DD} - Supply Voltage - V

4.5

3

3.5

APPLICATION INFORMATION

Power-Supply Considerations

Power-supply lines must be decoupled by a $0.01-\mu F$ to $0.1-\mu F$ capacitor with short leads placed close to the TSL230RD device package. A low-noise power supply is required to minimize jitter on output pulses.

Device Operational Details

The frequency at the output pin (OUT) is given by:

$$f_O = f_D + (R_e) (E_e)$$

where:

f_O is the output frequency

 f_D is the output frequency for dark condition ($E_e = 0$)

R_e is the device responsivity for a given wavelength of light given in kHz/(μW/cm²)

 $E_{\rm p}$ is the incident irradiance in $\mu W/cm^2$

 f_D is an output frequency resulting from leakage currents. As shown in the equation above, this frequency represents a light-independent term in the total output frequency f_D . At very low light levels, this dark frequency can be a significant portion of f_D . The dark frequency is temperature dependent. For optimum performance of any given device over the full output range, the value of f_D should be measured (in the absence of light) and later subtracted from subsequent light measurement (see Figure 1).

Input Interface

A low-impedance electrical connection between the device $\overline{\text{OE}}$ pin and the device GND pin is required for improved noise immunity.

Output Interface

The output of the device is designed to drive a standard TTL or CMOS logic input over short distances. If lines greater than 12 inches are used on the output, a buffer or line driver is recommended.

Sensitivity Adjustment

Sensitivity is controlled by two logic inputs, S0 and S1. Sensitivity is adjusted using an electronic iris technique — effectively an aperture control — to change the response of the device to a given amount of light. The sensitivity can be set to one of three levels: 1×, 10× or 100×, providing two decades of adjustment. This allows the responsivity of the device to be optimized to a given light level while preserving the full-scale output-frequency range. Changing of sensitivity also changes the effective photodiode area by the same factor.



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APPLICATION INFORMATION

Output-Frequency Scaling

Output-frequency scaling is controlled by two logic inputs, S2 and S3. Scaling is accomplished on chip by internally connecting the pulse-train output of the converter to a series of frequency dividers. Divided outputs available are divide-by 2, 10, 100, and 1 (no division). Divided outputs are 50 percent-duty-cycle square waves while the direct output (divide-by 1) is a fixed-pulse-width pulse train. Because division of the output frequency is accomplished by counting pulses of the principal (divide-by 1) frequency, the final-output period represents an average of n (where n is 2, 10, or 100) periods of the principal frequency. The output-scaling-counter registers are cleared upon the next pulse of the principal frequency after any transition of the S0, S1, S2, S3, or OE lines. The output goes high upon the next subsequent pulse of the principal frequency, beginning a new valid period. This minimizes the time delay between a change on the input lines and the resulting new output period in the divided output modes. In contrast with the sensitivity adjust, use of the divided outputs lowers both the full-scale frequency and the dark frequency by the selected scale factor.

The frequency-scaling function allows the output range to be optimized for a variety of measurement techniques. The divide-by-1 or straight-through output can be used with a frequency counter, pulse accumulator, or high-speed timer (period measurement). The divided-down outputs may be used where only a slower frequency counter is available, such as a low-cost microcontroller, or where period measurement techniques are used. The divide-by-10 and divide-by-100 outputs provide lower frequency ranges for high resolution-period measurement.

Measuring the Frequency

The choice of interface and measurement technique depends on the desired resolution and data acquisition rate. For maximum data-acquisition rate, period-measurement techniques are used.

Using the divide-by-2 output, data can be collected at a rate of twice the output frequency or one data point every microsecond for full-scale output. Period measurement requires the use of a fast reference clock with available resolution directly related to reference-clock rate. Output scaling can be used to increase the resolution for a given clock rate or to maximize resolution as the light input changes. Period measurement is used to measure rapidly varying light levels or to make a very fast measurement of a constant light source.

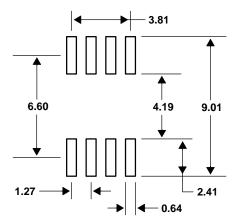
Maximum resolution and accuracy may be obtained using frequency-measurement, pulse-accumulation, or integration techniques. Frequency measurements provide the added benefit of averaging out random or high-frequency variations (jitter) resulting from noise in the light signal or from noise in the power supply. Resolution is limited mainly by available counter registers and allowable measurement time. Frequency measurement is well suited for slowly varying or constant light levels and for reading average light levels over short periods of time. Integration (the accumulation of pulses over a very long period of time) can be used to measure exposure, the amount of light present in an area over a given time period.



APPLICATION INFORMATION

PCB Pad Layout

Suggested PCB pad layout guidelines for the D package is shown in Figure 6.



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

Figure 6. Suggested D Package PCB Layout

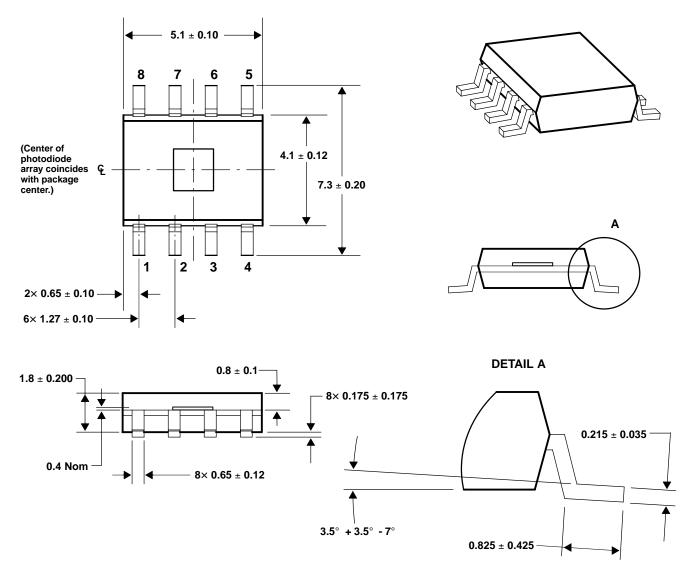
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MECHANICAL INFORMATION

This SOIC package consists of an integrated circuit mounted on a lead frame and encapsulated with an electrically nonconductive clear plastic compound. The TSL230RD has a 10×10 array of photodiodes with a total size of 0.96 mm by 0.96 mm. The photodiodes are 0.084 mm \times 0.084 mm in size and are positioned on 0.096 mm centers.

PACKAGE D

PLASTIC SMALL-OUTLINE



- NOTES: A. All linear dimensions are in millimeters.
 - B. Package is molded with an electrically nonconductive clear plastic compound having an index of refraction of 1.55.
 - C. Actual product will vary within the mechanical tolerances shown on this specification. Designs for use of this product MUST allow for the data sheet tolerances.
 - D. This drawing is subject to change without notice.

Figure 7. Package D — Plastic Small Outline IC Packaging Configuration

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